

# SPICE Device Model 2N7002E Vishay Siliconix

### N-Channel 60-V (D-S) MOSFET

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- · Macro Model (Subcircuit Model)
- Level 3 MOS

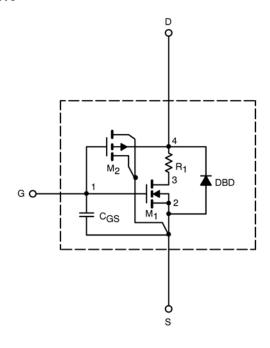
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

### **DESCRIPTION**

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125°C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\text{gd}}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_{D} = 250 \mu A$	3		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 10 V	3800		mA
Drain-Source On-State Resistance <sup>a</sup>	-	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.25 A	1.8	1.2	Ω
	r <sub>DS(on)</sub>	$V_{GS}$ = 4.5 V, $I_{D}$ = 0.20 A	2.4	1.8	
Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 0.20 A, V <sub>GS</sub> = 0 V	0.69	0.85	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 5 V, f = 1 MHz	31	21	Pf
Output Capacitance	C <sub>oss</sub>		11	7	
Reverse Transfer Capacitance	C <sub>rss</sub>		2	2.5	
Total Gate Charge <sup>c</sup>	Qg	$V_{DS}$ = 10 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 0.25 A	0.23	0.40	NC
Gate-Source Charge <sup>c</sup>	$Q_{gs}$		0.06	0.06	
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$		0.06	0.06	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>	$V_{DD} = 10 \text{ V, } R_L = 40 \Omega$ $I_D \cong 0.25 \text{ A, } V_{GEN} = 10 \text{ V, } R_G = 10 \Omega$	15	13	Ns
Turn-Off Delay Time <sup>c</sup>	$t_{d(off)}$		18	18	

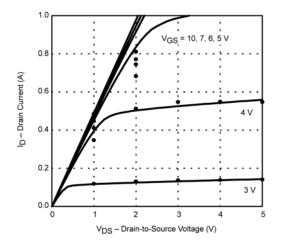
#### Notes

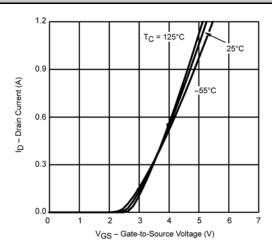
- a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2%.
  b. Guaranteed by design, not subject to production testing.
  c. Independent of operating temperature.

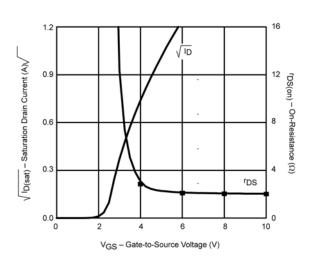


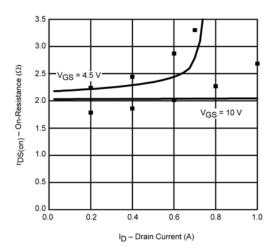
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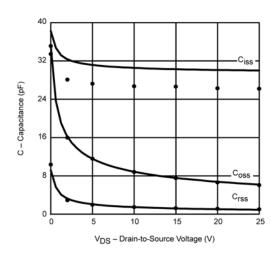
### COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

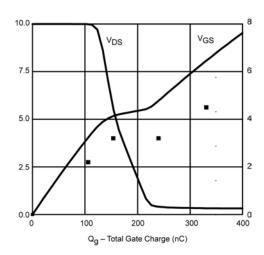












Note: Dots and squares represent measured data



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